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<u>Vishay Semiconductor/Diodes Division</u> <u>VSSC8L45-M3/9AT</u>

For any questions, you can email us directly: sales@integrated-circuit.com

VSSC8L45-M3

COMPLIANT

FREE



Vishay General Semiconductor

Surface Mount Trench MOS Barrier Schottky Rectifier



DO-214AB (SMC)

PRIMARY CHARACTERISTICS			
I _{F(AV)}	8.0 A		
V _{RRM}	45 V		
I _{FSM}	140 A		
V _F at I _F = 8.0 A (T _A = 125 °C)	0.39 V		
T _J max.	150 °C		
Package	DO-214AB (SMC)		
Diode variation	Single die		

FEATURES

- · Low profile package
- Ideal for automated placement
- Trench MOS Schottky technology
- Low power losses, high efficiency
- Low forward voltage drop
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Material categorization: For definitions of compliance please see www.vishay.com/doc?99912

TYPICAL APPLICATIONS

For use in high frequency converters, freewheeling diodes, DC/DC converters and polarity protection applications.

MECHANICAL DATA

Case: DO-214AB (SMC)

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free and RoHS-compliant, commercial grade

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Terminals: Matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 2 whisker test **Polarity:** Color band denotes the cathode end

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)				
PARAMETER	SYMBOL	VSSC8L45	UNIT	
Device marking code		8L45		
Maximum repetitive peak reverse voltage	V _{RRM}	45	V	
Maximum DC fanuard aurrent	I _F ⁽¹⁾	8.0	Α	
Maximum DC forward current	I _F ⁽²⁾	4.9		
Peak forward surge current 10 ms single half sine-wave superimposed on rated load	I _{FSM}	140	А	
Operating junction and storage temperature range	T _J , T _{STG}	-40 to +150	°C	

Notes

- (1) Units mounted on 3 cm x 3 cm Aluminum, 2 oz. PCB
- (2) Free air, mounted on recommended copper pad area

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Datasheet of VSSC8L45-M3/9AT - DIODE SCHOTTKY 45V 4.9A DO214AB Contact us: sales@integrated-circuit.com Website: www.integrated-circuit.com





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ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)						
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT
Instantaneous forward voltage	I _F = 4.0 A	- T _A = 25 °C	V _F ⁽¹⁾	0.42	-	. V
	I _F = 8.0 A			0.48	0.56	
	I _F = 4.0 A	T _A = 125 °C		0.32	-	
	I _F = 8.0 A			0.39	0.48	
Reverse current	V _R = 45 V	T _A = 25 °C	1 (2)	-	1.85	mA
	V _R = 45 V T _A = 125 °C	I _R ⁽²⁾	13	40	IIIA	
Typical junction capacitance	4.0 V, 1 MHz		CJ	1216	-	pF

Notes

- (1) Pulse test: 300 µs pulse width, 1 % duty cycle
- (2) Pulse test: Pulse width ≤ 5 ms

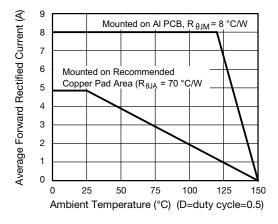
THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)				
PARAMETER	SYMBOL	VSSC8L45	UNIT	
Typical they mal registance	R _{0JA} (1)	70	°C/W	
Typical thermal resistance	R _{0JM} (2)	8		

Notes

- $^{(1)}$ Free air, mounted on recommended PCB 2 oz. pad area; thermal resistance $R_{\theta JA}$ junction to ambient
- (2) Units mounted on 3 cm x 3 cm Aluminum, 2 oz. pad area; thermal resistance $R_{\theta JM}$ junction to mount

ORDERING INFORMATION (Example)					
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE	
VSSC8L45-M3/57T	0.235	57T	850	7" diameter plastic tape and reel	
VSSC8L45-M3/9AT	0.235	9AT	3500	13" diameter plastic tape and reel	

RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)





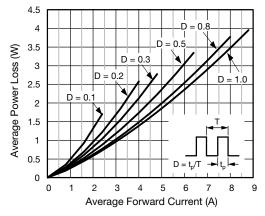


Fig. 2 - Forward Power Loss Characteristics

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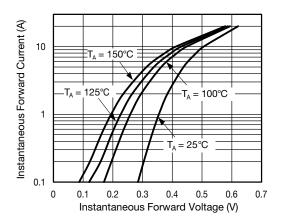


Fig. 3 - Typical Instantaneous Forward Characteristics

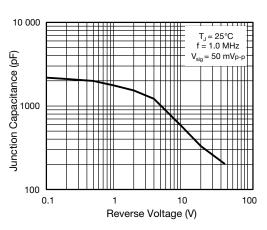


Fig. 5 - Typical Junction Capacitance

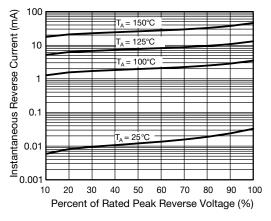


Fig. 4 - Typical Reverse Characteristics

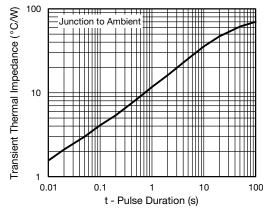
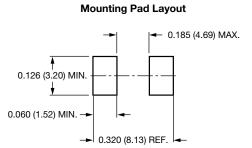


Fig. 6 - Typical Transient Thermal Impedance

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

DO-214AB (SMC) Cathode Band 0.246 (6.22) 0.126 (3.20) 0.220 (5.59) 0.114 (2.90) 0.280 (7.11) 0.260 (6.60) 0.012 (0.305) 0.006 (0.152) 0.103 (2.62) 0.079 (2.06) 0.008 (0.2) 0.060 (1.52) 0.030 (0.76) 0 (0) 0.320 (8.13) 0.305 (7.75)



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